NSN 5961-01-290-3852

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-290-3852 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, instantaneous and 1.0 forward voltage, dc **Current Rating Per Characteristic:** 100.00 nanoamperes forward current, average outside diameter **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 0.25 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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